1.5V Drive Pch MOSFET

RZL025P01

●Structure

Silicon P-channel MOSFET

● Features

- 1) Low on-resistance.
- 2) High power package.
- 3) Low voltage drive. (1.5V)

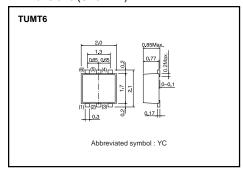
Application

Switching

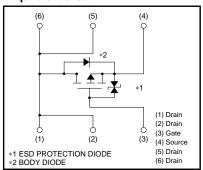
Packaging specifications

	Package	Taping
Туре	Code	TR
	Basic ordering unit (pieces)	3000
RZL025P01	0	

●Dimensions (Unit: mm)



●Equivalent circuit



● Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit	
Drain-source voltage		V _{DSS}	-12	V	
Gate-source voltage		V_{GSS}	±10	V	
Drain current	Continuous	I _D	±2.5	Α	
	Pulsed	I _{DP} *1	±10	Α	
Source current	Continuous	Is	-0.8	А	
(Body diode)	Pulsed	I _{SP} *1	-10	А	
Total power dissipation		P _D *2	1.0	W	
Channel temperature		Tch	150	°C	
Range of Storage temperature		Tstg	-55 to +150	°C	

^{*1} Pw≤10μs, Duty cycle≤1%

Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to ambient	Rth (ch-a) *	125	°C/W

^{*} When mounted on a ceramic board.

^{*2} Mounted on a ceramic board

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Gate-source leakage	I _{GSS}	-	-	±10	μΑ	V _{GS} =±10V, V _{DS} =0V
Drain-source breakdown voltage	V(BR) DSS	-12	-	-	V	In=-1mA, Vgs=0V
Zero gate voltage drain current	I _{DSS}	_	_	-1	μΑ	V _{DS} = -12V, V _{GS} =0V
Gate threshold voltage	VGS (th)	-0.3	-	-1.0	V	VDS= -6V, ID= -1mA
Static drain-source on-state resistance	R _{DS} (on)*	_	44	61	mΩ	I _D = -2.5A, V _G S= -4.5V
		_	60	84	mΩ	I _D = -1.2A, V _G S= -2.5V
		-	81	121	mΩ	I _D = -1.2A, V _{GS} = -1.8V
		-	110	220	mΩ	I _D = -0.5A, V _G S= -1.5V
Forward transfer admittance	Y _{fs} *	3.5	_	_	S	V _{DS} = -6V, I _D = -2.5A
Input capacitance	Ciss	-	1350	-	pF	V _{DS} = -6V
Output capacitance	Coss	-	130	-	pF	V _{GS} =0V
Reverse transfer capacitance	Crss	_	125	_	pF	f=1MHz
Turn-on delay time	t d (on) *	-	9	_	ns	I _D = -1.2A
Rise time	tr *	_	35	_	ns	VDD≒ -6V
Turn-off delay time	td (off) *	-	130	_	ns	$V_{GS} = -4.5V$ $R_L = 5\Omega$
Fall time	t _f *	-	85	-	ns	R _G =10Ω
Total gate charge	Qg *	_	13	_	nC	V _{DD} ≒-6V, I _D =-2.5A
Gate-source charge	Q _{gs} *	-	2.5	-	nC	V _{GS} = -4.5V
Gate-drain charge	Q _{gd} *	-	2.0	-	nC	$R_L = 2.4\Omega$, $R_G=10\Omega$

^{*}Pulsed

●Body diode characteristics(Source-drain) (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward voltage	V _{SD} *	_	-	-1.2	V	I _S = -2.5A, V _{GS} =0V

^{*} Pulsed

Electrical characteristic curves

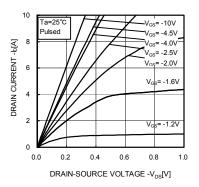


Fig.1 Typical Output Characteristics(I)

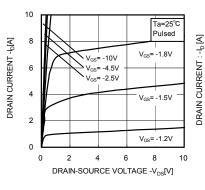


Fig.2 Typical Output Characteristics(II)

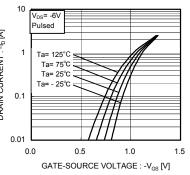


Fig.3 Typical Transfer Characteristics

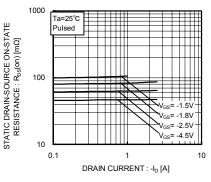


Fig.4 Static Drain-Source On-State Resistance vs. Drain Current(I)

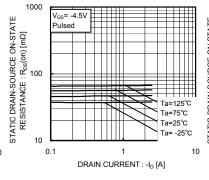


Fig.5 Static Drain-Source On-State Resistance vs. Drain Current(II)

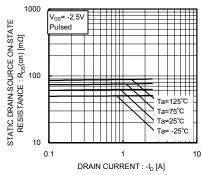


Fig.6 Static Drain-Source On-State Resistance vs. Drain Current(Ⅲ)

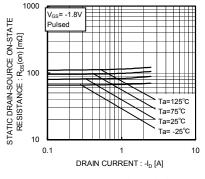


Fig.7 Static Drain-Source On-State Resistance vs. Drain Current(IV)

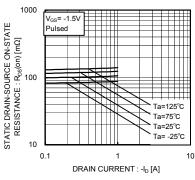


Fig.8 Static Drain-Source On-State Resistance vs. Drain Current(IV)

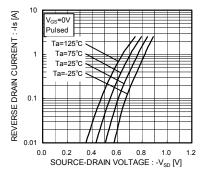


Fig.9 Reverse Drain Current vs. Sourse-Drain Voltage

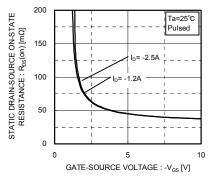


Fig.10 Static Drain-Source On-State
Resistance vs. Gate Source Voltage

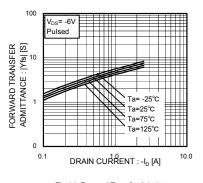


Fig.11 Forward Transfer Admittance vs. Drain Current

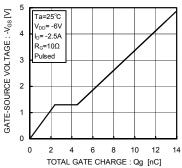


Fig.12 Dynamic Input Characteristics

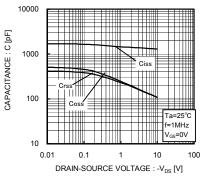


Fig.13 Typical Capacitance vs. Drain-Source Voltage

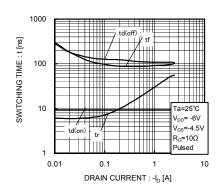


Fig.14 Switching Characteristics

Measurement circuits

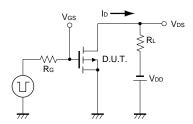


Fig.15 Switching Time Test Circuit

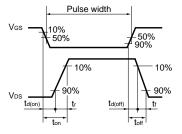


Fig.16 Switching Time Waveforms

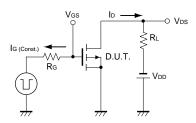


Fig.17 Gate Charge Test Circuit

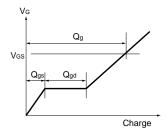


Fig.18 Gate Charge Waveform

●Notice

This product might cause chip aging and breakdown under the large electrified environment. Please consider to design ESD protection circuit.

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Appendix1-Rev2.0